

Excellent Integrated System Limited

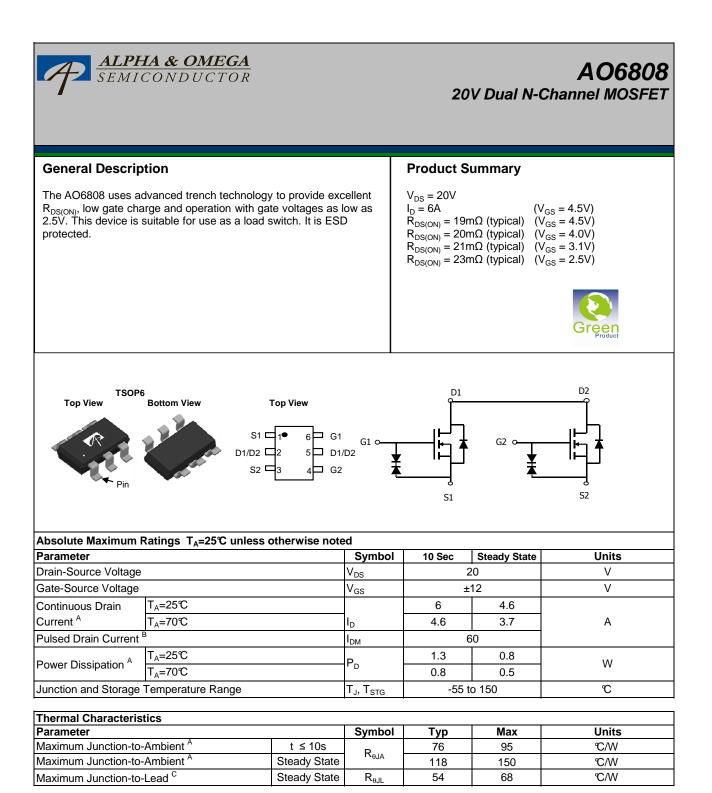
Stocking Distributor

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Alpha & Omega Semiconductor Inc. AO6808

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>









Electrical Characteristics (T_J=25℃ unless otherwise noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Units	
STATIC P	PARAMETERS							
BV _{DSS}	Drain-Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$		20			V	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 20V, V_{GS} = 0V$				1	μA	
		T _J = 55℃				5	μΑ	
I _{GSS}	Gate-Body leakage current	$V_{DS} = 0V, V_{GS} = \pm 10V$				±10	μA	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS} I_D = 250 \mu A$		0.5	0.75	1	V	
I _{D(ON)}	On state drain current	$V_{GS} = 4.5V, V_{DS} = 5V$		60			А	
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = 4.5V, I_{D} = 6.0A$		15	19	23	mΩ	
		Т	_=125℃	21	27	33	11152	
		$V_{GS} = 4.0V, I_{D} = 5.5A$		15	20	25	mΩ	
		$V_{GS} = 3.1V, I_{D} = 5A$		16	21	27	mΩ	
		$V_{GS} = 2.5V, I_{D} = 2A$		17	23	30	mΩ	
g _{fs}	Forward Transconductance	$V_{DS} = 5V, I_{D} = 6.0A$			34		S	
V _{SD}	Diode Forward Voltage	$I_S = 1A, V_{GS} = 0V$			0.65	1	V	
ls	Maximum Body-Diode Continuous Current					1.3	А	
DYNAMIC	PARAMETERS							
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =10V, f=1MHz			620	780	pF	
C _{oss}	Output Capacitance				125		pF	
C _{rss}	Reverse Transfer Capacitance				64		pF	
SWITCHI	NG PARAMETERS							
Q _g (10V)	Total Gate Charge	V _{GS} = 10V, V _{DS} = 10V, I _D = 6A			16.2	21	nC	
Q _g (4.5V)	Total Gate Charge				7.7	10	nC	
Q _{gs}	Gate Source Charge				1.5		nC	
Q_{gd}	Gate Drain Charge				2.7		nC	
t _{D(on)}	Turn-On DelayTime	V_{GS} =10V, V_{DS} =10V, R_{L} =1.7 Ω , R_{GEN} =3 Ω			236		ns	
t _r	Turn-On Rise Time				448		ns	
t _{D(off)}	Turn-Off DelayTime				9.5		μs	
t _f	Turn-Off Fall Time				4.1		μs	
t _{rr}	Body Diode Reverse Recovery Time	I _F =6A, dl/dt=100A/μs			25	33	ns	
Q _{rr}	Body Diode Reverse Recovery Charge	I _F =6A, dl/dt=100A/μs			9		nC	

A: The value of R_{0JA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A = 25° C. in any given application depends on the user's specific board design. The current rating is based on the t <10s thermal resistance rating. B: Repetitive rating, pulse width limited by junction temperature.

C. The R $_{\text{BJA}}$ is the sum of the thermal impedence from junction to lead R $_{\text{BJL}}$ and lead to ambient.

D. The static characteristics in Figures 1 to 6 are obtained using < 300μ s pulses, duty cycle 0.5% max. E. These tests are performed with the device mounted on 1 in ² FR-4 board with 2oz. Copper, in a still air environment with T_A=25° C. The SOA curve provides a single pulse rating.

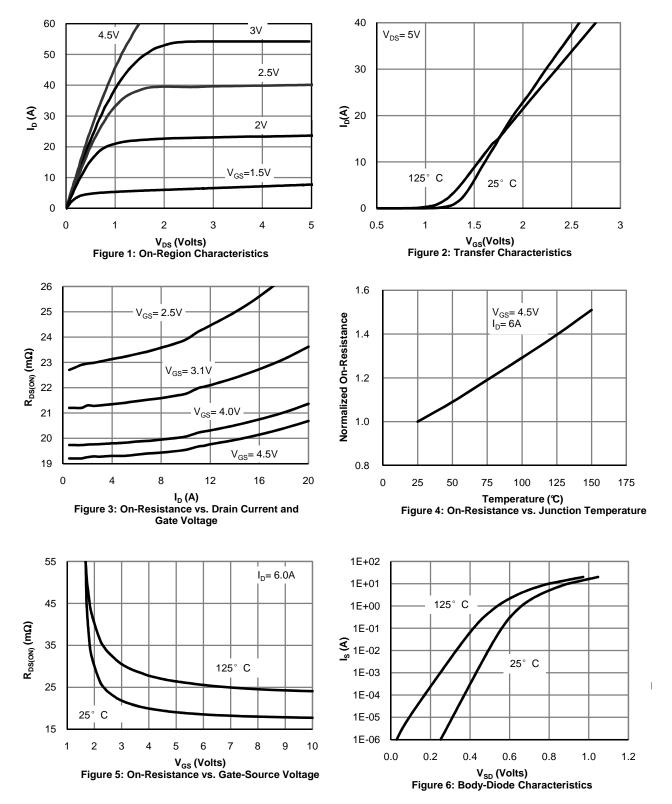
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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

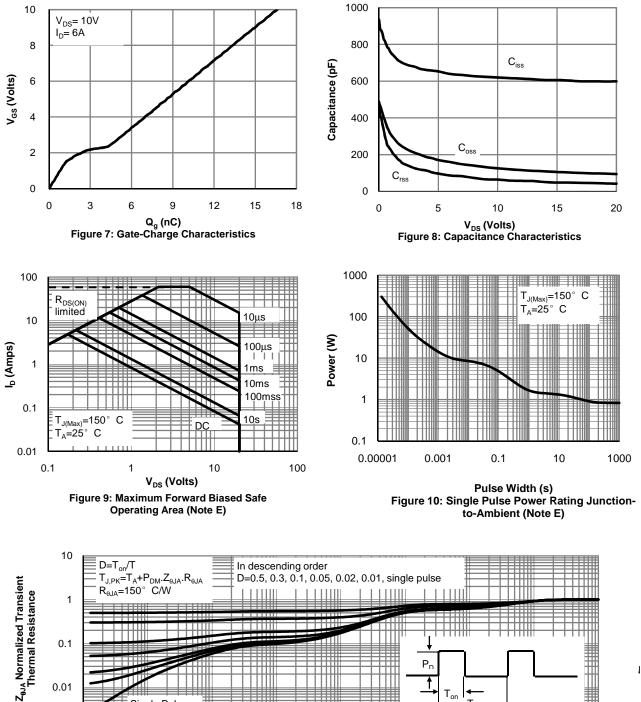




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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



1

10

100



0.1

0.01

0.001

0.00001

Single Pulse

0.001

0.0001

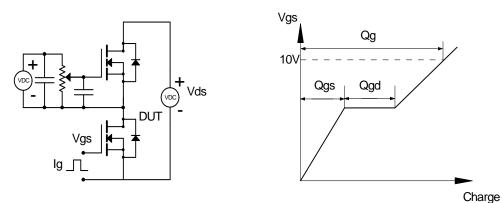
1000



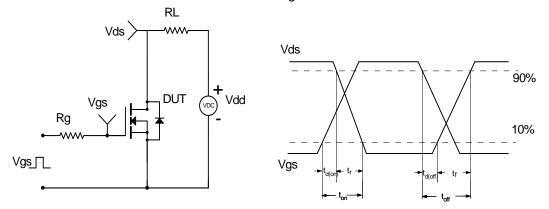
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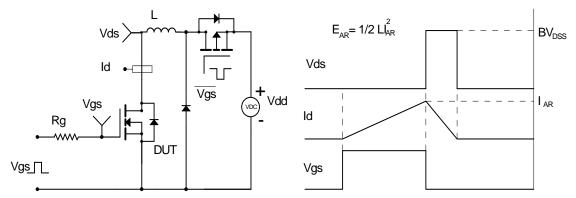
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms

